## **PATENT APPLICATION**

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of

Izumi FUSEGAWA et al.

Application No.: New U.S. National Stage of

PCT/JP03/05167

Filed: October 8, 2004 Docket No.: 121356

For: METHOD OF MANUFACTURING SILICON SINGLE CRYSTAL, SILICON SINGLE

CRYSTAL AND SILICON WAFER

## **PRELIMINARY AMENDMENT**

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

Please consider the following:

Amendments to the Specification;

Amendments to the Claims as reflected in the listing of claims;

Remarks.